

MC75172BDWR2G Datasheet

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DiGi Electronics Part Number MC75172BDWR2G-DG Manufacturer onsemi Manufacturer Product Number MC75172BDWR2G Description IC DRIVER 4/0 20SOIC Detailed Description 4/0 Driver RS422, RS485 20-SOIC

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MC75172BDWR2G	onsemi
Series:	Product Status:
	Obsolete
Туре:	Protocol:
Driver	RS422, RS485
Number of Drivers/Receivers:	Duplex:
4/0	-
Data Rate:	Voltage - Supply:
10Mbps	4.75V ~ 5.25V
Operating Temperature:	Mounting Type:
-40°C ~ 85°C	Surface Mount
Package / Case:	Supplier Device Package:
20-SOIC (0.295", 7.50mm Width)	20-SOIC
Base Product Number:	
MC75172	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
3 (168 Hours)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8542.39.0001

Quad EIA-485 Line Drivers with Three-State Outputs

The ON Semiconductor MC75172B/174B Quad Line drivers are differential high speed drivers designed to comply with the EIA-485 Standard. Features include three-state outputs, thermal shutdown, and output current limiting in both directions. These devices also comply with EIA-422-A, and CCITT Recommendations V.11 and X.27.

The MC75172B/174B are optimized for balanced multipoint bus transmission at rates in excess of 10 MBPS. The outputs feature wide common mode voltage range, making them suitable for party line applications in noisy environments. The current limit and thermal shutdown features protect the devices from line fault conditions. These devices offer optimum performance when used with the MC75173 and MC75175 line receivers.

Both devices are available in 16-pin plastic PDIP and 20-pin wide body surface mount packages.

Features

- Meets EIA-485 Standard for Party Line Operation
- Meets EIA-422-A and CCITT Recommendations V.11 and X.27
- Operating Ambient Temperature: -40°C to +85°C
- High Impedance Outputs
- Common Mode Output Voltage Range: -7.0 to 12 V
- Positive and Negative Current Limiting
- Transmission Rates in Excess of 10 MBPS
- Thermal Shutdown at 150°C Junction Temperature, (±20°C)
- Single 5.0 V Supply
- Pin Compatible with TI SN75172/4 and NS μ A96172/4
- Interchangeable with MC3487 and AM26LS31 for EIA-422-A Applications
- Pb–Free Packages are Available*

MAXIMUM RATING

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	-0.5, +7.0	Vdc
Input Voltage (Data, Enable)	V _{in}	+7.0	Vdc
Input Current (Data, Enable)	l _{in}	-24	mA
Applied Output Voltage, when in 3–State Condition ($V_{CC} = 5.0 \text{ V}$)	V _{za}	–10, +14	Vdc
Applied Output Voltage, when $V_{CC} = 0 V$	V _{zb}	±14	Vdc
Output Current	Ι _Ο	Self-Limiting	-
Storage Temperature	T _{stg}	-65, +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Devices should not be operated at these limits. The "Recommended Operating Conditions" table provides for actual device operation.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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QUAD EIA-485 LINE DRIVERS





PDIP-16 P SUFFIX CASE 648



MARKING DIAGRAMS MC17517xBDW AWLYYWWG 8888888888 MC75174BP AWLYYWWG Ο ᠂ᡝᢧᢑᢑᢑᢑᢑᢑᢑᡆᡁ = 2 or 4 х Α = Assembly Location WL = Wafer Lot YY = Year WW = Work Week G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Min	Тур	Max	Unit
Power Supply Voltage	V _{CC}	+4.75	+5.0	+5.25	Vdc
Input Voltage (All Inputs)	V _{in}	0	-	V _{CC}	Vdc
Output Voltage in 3–State Condition, or when $V_{CC} = 0 V$	V _{cm}	-7.0	-	+12	Vdc
Output Current (Normal data transmission)	Ι _Ο	-65	-	+65	mA
Operating Ambient Temperature (see text) EIA-485 EIA-422	T _A	-40 0	-	+85	°C

2. All limits are not necessarily functional concurrently.

ELECTRICAL CHARACTERISTICS (-40°C \leq T_A \leq 85°C, 4.75 V \leq V_{CC} \leq 5.25 V, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage Single–Ended Voltage $I_0 = 0$ High @ $I_0 = -33$ mA Low @ $I_0 = +33$ mA Differential Voltage Open Circuit ($I_0 = 0$) $R_L = 54 \Omega$ (Figure 1)	V ₀ V _{0H} V _{0L} V _{0D1} V _{0D2}	0 - - 1.5 1.5	- 4.0 1.6 3.4 2.3	6.0 - - 6.0 5.0	Vdc
Change in Differential*, $R_L = 54 \Omega$ (Figure 1) Differential Voltage, $R_L = 100 \Omega$ (Figure 1) Change in Differential*, $R_L = 100 \Omega$ (Figure 1) Differential Voltage, $-7.0 V \le V_{cm} \le 12 V$ (Figure 2) Change in Differential*, $-7.0 V \le V_{cm} \le 12 V$ (Figure 2) Offset Voltage, $R_L = 54 \Omega$ (Figure 1) Change in Offset*, $R_L = 54 \Omega$ (Figure 1)	$\begin{vmatrix} \Delta V_{OD2} \\ V_{OD2A} \\ \Delta V_{OD2A} \\ \Delta V_{OD3} \\ \Delta V_{OD3} \\ \Delta V_{OD3} \\ V_{OS} \\ \Delta V_{OS} \end{vmatrix}$	- - 1.5 - -	5.0 2.2 5.0 - 5.0 2.9 5.0	200 - 200 5.0 200 - 200	mVdc Vdc mVdc Vdc mVdc Vdc mVdc
Output Current (Each Output) Power Off Leakage, $V_{CC} = 0, -7.0 \text{ V} \le V_O \le 12 \text{ V}$ Leakage in 3–State Mode, -7.0 V $\le V_O \le 12 \text{ V}$	I _{O(off)} I _{OZ}	-50 -50	0 0	+50 +50	μΑ
Short Circuit Current to Ground Short Circuit Current, $-7.0 \text{ V} \le \text{V}_0 \le 12 \text{ V}$	I _{OSR} I _{OS}	-150 -250		+150 +250	mA
Inputs Low Level Voltage (Pins 4 & 12, MC75174B only) Low Level Voltage (All Other Pins) High Level Voltage (All Inputs)	V _{IL(A)} VIL(B) VIH	0 0 2.0	- - -	0.7 0.8 V _{CC}	Vdc
Current @ $V_{in} = 2.7 V$ (All Inputs) Current @ $V_{in} = 0.5 V$ (All Inputs)	I _{IH} I _{IL}	_ _100	0.2 -15	20 -	μΑ
Clamp Voltage (All Inputs, I _{in} = -18 mA)	V _{IK}	-1.5	-	-	Vdc
Thermal Shutdown Junction Temperature	T _{jts}	-	+150	-	°C
Power Supply Current (Outputs Open, V _{CC} = 5.25 V) Outputs Enable Outputs Disabled	Icc		60 30	70 40	mA

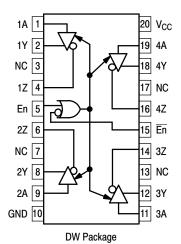
3. *V_{in} switched from 0.8 to 2.0 V. Typical values determined at 25°C ambient and 5.0 V supply.

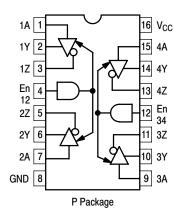
TIMING CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

Characteristics	Symbol	Min	Тур	Max	Unit
Propagation Delay – Input to Single–ended Output (Figure 3) Output Low–to–High Output High–to–Low	t _{PLH} t _{PHL}		23 18	30 30	ns
Propagation Delay – Input to Differential Output (Figure 4) Input Low-to-High Input High-to-Low	^t PLH(D) ^t PHL(D)		15 17	25 25	ns
Differential Output Transition Time (Figure 4)	t _{dr} , t _{df}	-	19	25	ns
Skew Timing	tskı tsk2 tsk3	- - -	0.2 1.5 1.5	- - -	ns
Enable Timing Single-ended Outputs (Figure 5) Enable to Active High Output Enable to Active Low Output Active High to Disable (using Enable) Active Low to Disable (using Enable) Enable to Active High Output (MC75172B only) Enable to Active Low Output (MC75172B only) Active High to Disable (using Enable, MC75172B only) Active Low to Disable (using Enable, MC75172B only)	tpzh(E) tpzL(E) tphz(E) tplz(E) tpzh(E) tpzh(E) tpzL(E) tphz(E) tplz(E)		48 20 35 30 58 28 38 38 36	60 30 45 50 70 35 50 50	ns
Differential Outputs (Figure 6) <u>Enable</u> to Active Output Enable to Active Output (MC75172B only) <u>Enable</u> to 3–State Output <u>Enable</u> to 3–State Output (MC75172B only)	tpzd(E) tpzd(E) tpdz(E) tpdz(E) tpdz(E)	- - - -	47 56 32 40	- - -	ns

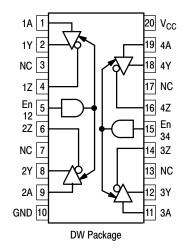
PIN CONNECTIONS

MC75172B





MC75174B



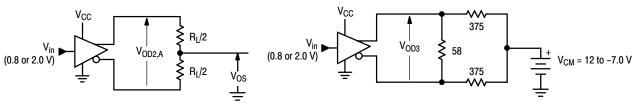


Figure 1. V_{DD} Measurement

Figure 2. Common Mode Test

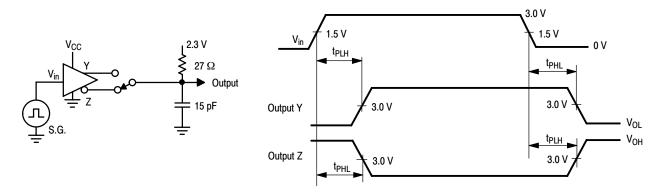
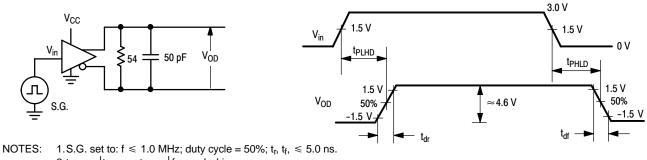


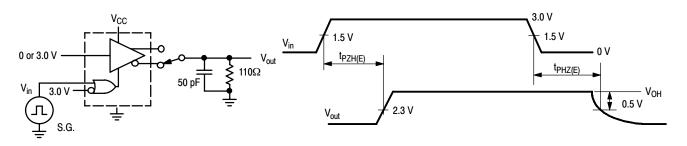
Figure 3. Propagation Delay, Single-Ended Outputs



2. $t_{SK3} = |t_{PLHD} - t_{PHLD}|$ for each driver. 3. t_{SK2} computed by subtracting the shortest t_{PLHD} from the longest t_{PLHD} of the 4 drivers within a package. 4. t_{SK3} computed by subtracting the shortest t_{PHLD} from the longest t_{PHLD} of the 4 drivers within a package.

Figure 4. Propagation Delay, Differential Outputs

MC75172B, MC75174B



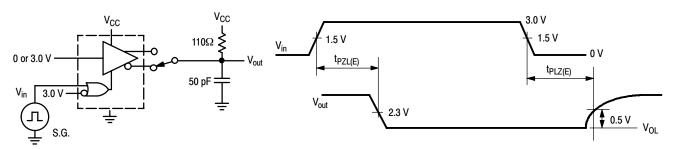
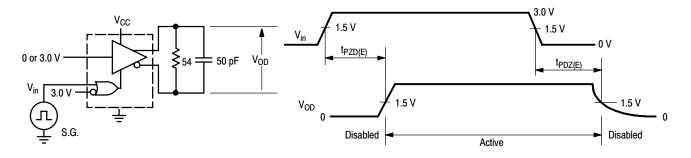
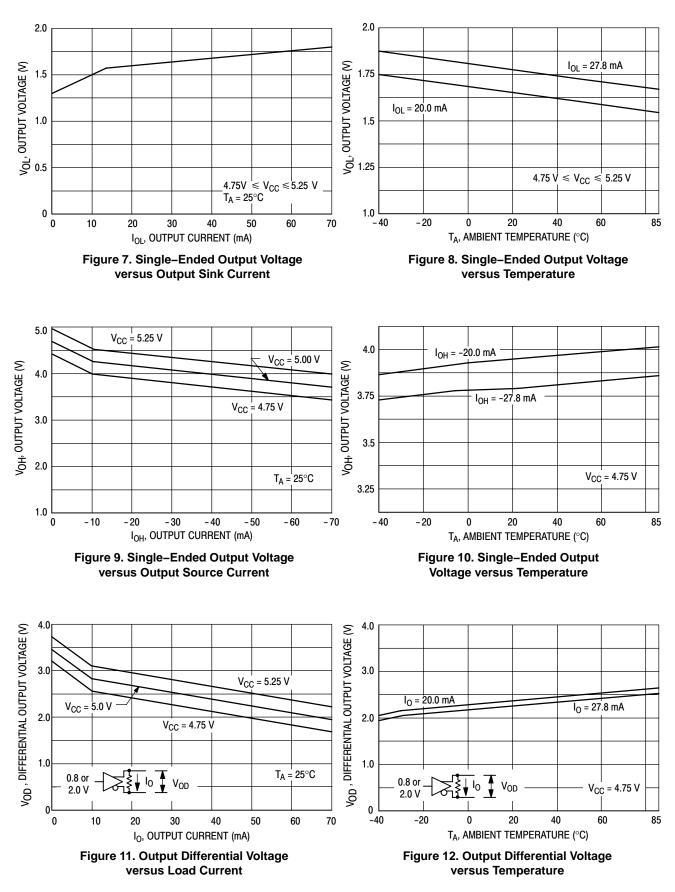


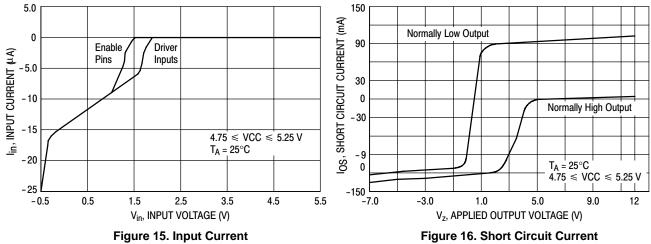
Figure 5. Enable Timing, Single-Ended Outputs







2.0 20 15 IOZ, LEAKAGE CURRENT (µ A) IOZ, LEAKAGE CURRENT (µA) 1.0 10 5.0 V_{out} = +12 V 0 0 V_{out} = 7.0 V -5.0 -1.0 -10 lox, I T_A = 25°C $\dot{E}n = Low, \overline{En} = High$ -15 En = Low, En = Highor $V_{CC} = 0 V$ -2.0 -20 -7.0 -3.0 1.0 5.0 9.0 12 -40 -20 0 20 40 60 85 V_z, APPLIED OUTPUT VOLTAGE (V) T_A, AMBIENT TEMPERATURE (°C) Figure 13. Output Leakage Current Figure 14. Output Leakage Current versus Output Voltage versus Temperature



versus Input Voltage

Figure 16. Short Circuit Current versus Common Mode Voltage

APPLICATIONS INFORMATION

Description

The MC75172B and MC75174B are differential line drivers designed to comply with EIA–485 Standard (April 1983) for use in balanced digital multipoint systems containing multiple drivers. The drivers also comply with EIA–422–A and CCITT Recommendations V.11 and X.27. The drivers meet the EIA–485 requirement for protection from damage in the event that two or more drivers attempt to transmit data simultaneously on the same cable. Data rates in excess of 10 MBPS are possible, depending on the cable length and cable characteristics. A single power supply, 5.0 V, \pm 5%, is required at a nominal current of 60 mA, plus load currents.

Outputs

Each output (when active) will be a low or a high voltage, which depends on the input state and the load current (see Table 1, 2 and Figures 7 to 10). The graphs apply to each driver, regardless of how many other drivers within the package are supplying load current.

	Enables		Out	puts
Data Input	EN	EN	Y	Z
Н	Н	Х	Н	L
L	Н	Х	L	Н
Н	Х	L	н	L
L	Х	L	L	Н
Х	L	н	Z	Z

Table 1. MC75172B Truth Table

Table 2. MC75174B Truth Table

		Outputs	
Data Input	Enable	Y	Z
Н	Н	Н	L
L	Н	L	Н
Х	L	Z	Z

H = Logic high, L = Logic low, X = Irrelevant, Z = High impedance

The two outputs of a driver are always complementary. A "high" output can only source current out, while a "low" output can only sink current (except for short circuit current – see Figure 16).

The outputs will be in the high impedance mode when:

- a) the Enable inputs are set according to Table 1 or 2;
- b) V_{CC} is less than 1.5 V;
- c) the junction temperature exceeds the trip point of the thermal shutdown circuit (see below). When in this condition, the output's source and sink capability are shut off, and only leakage currents will flow (see Figures 13, 14). Disabled outputs may be taken to any voltage between -7.0 V and 12 V without damage.

The drivers are protected from short circuits by two methods:

- a) Current limiting is provided at each output, in both the source and sink direction, for shorts to any voltage within the range of 12 V to −7.0 V, with respect to circuit ground (see Figure 16). The short circuit current will flow until the fault is removed, or until the thermal shutdown circuit activates (see below). The current limiting circuit has a negative temperature coefficient and requires no resetting upon removal of the fault condition.
- b) A thermal shutdown circuit disables the outputs when the junction temperature reaches 150° C, $\pm 20^{\circ}$ C. The thermal shutdown circuit has a hysteresis of $\approx 12^{\circ}$ C to prevent oscillations. When this circuit activates, the output stage of each driver is put into the high impedance mode, thereby shutting off the output currents. The remainder of the internal circuitry remains biased. The outputs will become active once again as the IC cools down.

Driver Inputs

The driver inputs determine the state of the outputs in accordance with Tables 1 and 2. The driver inputs have a nominal threshold of 1.2 V, and their voltage must be kept within the range of 0 V to V_{CC} for proper operation. If the voltage is taken more than 0.5 V below ground, excessive currents will flow, and proper operation of the drivers will be affected. An open pin is equivalent to a logic high, but good design practices dictate that inputs should never be left open. The characteristics of the driver inputs are shown in Figure 15. This graph is not affected by the state of the Enable pins.

Enable Logic

Each driver's outputs are active when the Enable inputs (Pins 4 and 12) are true according to Tables 1 and 2.

The Enable inputs have a nominal threshold of 1.2 V and their voltage must be kept within the range of 0 V to V_{CC} for proper operation. If the voltage is taken more than 0.5 V below ground, excessive currents will flow, and proper operation of the drivers will be affected. An open pin is equivalent to a logic high, but good design practices dictate that inputs should never be left open. The Enable input characteristics are shown in Figure 15.

Operating Temperature Range

The minimum ambient operating temperature is listed as -40° C to meet EIA-485 specifications, and 0°C to meet EIA-422-A specifications. The higher V_{OD} required by EIA-422-A is the reason for the narrower temperature range.

The maximum ambient operating temperature (applicable to both EIA–485 and EIA–422–A) is listed as 85°C. However, a lower ambient may be required depending on system use (i.e. specifically how many drivers within a package are used) and at what current levels they are operating. The maximum power which may be dissipated within the package is determined by:

$$PD_{max} = \frac{T_{Jmax} - T_{A}}{R_{\theta JA}}$$

where:

 $R_{\theta JA}$ = package thermal resistance (typical 70°C/W for the DIP package, 85°C/W for SOIC package); T_{Jmax} = max. operating junction temperature, and

 T_A = ambient temperature.

Since the thermal shutdown feature has a trip point of 150° C, $\pm 20^{\circ}$ C, T_{Jmax} is selected to be 130° C. The power dissipated within the package is calculated from:

PD	$= \{ [(V_{CC} - V_{OH}) \bullet I_{OH}] + V_{OL} \bullet I_{OL}) \} \text{ each}$
	driver + ($V_{CC} \bullet I_{CC}$)
where:	V_{CC} = the supply voltage;
	V _{OH} , V _{OL} are measured or estimated from
	Figures 7 to 10;
	I _{CC} = the quiescent power supply current
	(typical 60 mA).

As indicated in the equation, the first term (in brackets) must be calculated and summed for each of the four drivers, while the last term is common to the entire package.

Example 1: $T_A = 25^{\circ}C$, $I_{OL} = I_{OH} = 55$ mA for each driver, $V_{CC} = 5.0$ V, DIP package. How many drivers per package can be used?

Maximum allowable power dissipation is:

$$PD_{max} = \frac{130^{\circ}C - 25^{\circ}C}{70^{\circ}C/W} = 1.5 W$$

Since the power supply current of 60 mA dissipates 300 mW, that leaves 1.2 W (1.5 W – 0.3 W) for the drivers. From Figures 7 and 9, $V_{OL} \approx 1.75$ V, and $V_{OH} \approx 3.85$ V. The power dissipated in each driver is:

 $\{(5.0 - 3.85) \bullet 0.055\} + (1.75 \bullet 0.055) = 160 \text{ mW}.$

Since each driver dissipates 160 mW, the four drivers per package could be used in this application.

Example 2: $T_A = 85^{\circ}C$, $I_{OL} = 27.8 \text{ mA}$, $I_{OH} = 20 \text{ mA}$ for each driver, $V_{CC} = 5.0 \text{ V}$, SOIC package. How many drivers per package can be used?

Maximum allowable power dissipation is:

$$PD_{max} = \frac{130^{\circ}C - 85^{\circ}C}{85^{\circ}C/W} = 0.53 W$$

Since the power supply current of 60 mA dissipates 300 mW, that leaves 230 mW (530 mW - 300 mW) for the

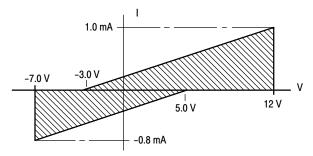
drivers. From Figures 8 and 10 (adjusted for $V_{CC} = 5.0 \text{ V}$), $V_{OL} \approx 1.38 \text{ V}$, and $V_{OH} \approx 4.27 \text{ V}$. The power dissipated in each driver is:

 $\{(5.0 - 4.27) \bullet 0.020\} + (1.38 \bullet 0.0278) = 53 \text{ mW}$

Since each driver dissipates 53 mW, the use of all four drivers in a package would be marginal. Options include reducing the load current, reducing the ambient temperature, and/or providing a heat sink.

System Requirements

EIA-485 requires each driver to be capable of transmitting data differentially to at least 32 unit loads, plus an equivalent DC termination resistance of 60Ω , over a common mode voltage of -7.0 to 12 V. A unit load (U.L.), as defined by EIA-485, is shown in Figure 17.



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Figure 17. Unit Load Definition

A load current within the shaded regions represents an impedance of less than one U.L., while a load current of a magnitude outside the shaded area is greater than one U.L. A system's total load is the sum of the unit load equivalents of each receiver's input current, and each disabled driver's output leakage current. The 60Ω termination resistance mentioned above allows for two 120Ω terminating resistors.

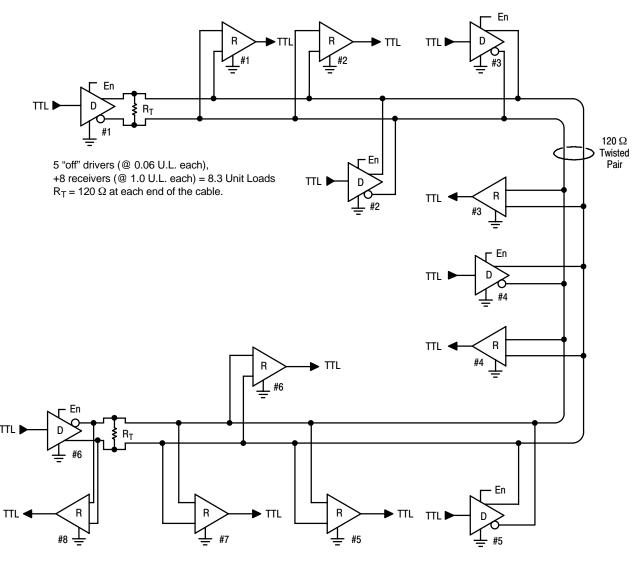
Using the EIA–485 requirements (worst case limits), and the graphs of Figures 7 and 9, it can be determined that the maximum current an MC75172B or MC75174B driver will source or sink is ≈ 65 mA.

System Example

An example of a typical EIA–485 system is shown in Figure 18. In this example, it is assumed each receiver's input characteristics correspond to 1.0 U.L. as defined in Figure 17. Each "off" driver, with a maximum leakage of $\pm 50 \,\mu\text{A}$ over the common mode range, presents a load of $\approx 0.06 \,\text{U.L}$. The total load for the active driver is therefore 8.3 unit loads, plus the parallel combination of the two terminating resistors (60Ω). It is up to the system software to control the driver Enable pins to ensure that only one driver is active at any time.

Termination Resistors

Transmission line theory states that, in order to preserve the shape and integrity of a waveform traveling along a cable, the cable must be terminated in an impedance equal to its characteristic impedance. In a system such as that depicted in Figure 18, in which data can travel in both directions, both physical ends of the cable must be terminated. Stubs, leading to each receiver and driver, should be as short as possible. Leaving off the terminations will generally result in reflections which can have amplitudes of several volts above V_{CC} or below ground. These overshoots and undershoots can disrupt the driver and/or receiver operation, create false data, and in some cases damage components on the bus.



NOTES: 1. Terminating resistors RT must be located at the physical ends of the cable.

2. Stubs should be as short as possible.

 Circuit ground of all drivers and receivers must be connected via a dedicated wire within the cable. Do not rely on chassis ground or power line ground.



MC75172BDWR2G onsemi IC DRIVER 4/0 20SOIC

MC75172B, MC75174B

COMPARING SYSTEM REQUIREMENTS

Symbol	EIA-485	EIA-422-A	V.11 and X.27
	'	'	
Z _{out}	Not Specified	< 100 Ω	50 10 100 Ω
V _{OCD} V _{OCS}	1.5 to 6.0 V < 6.0 V	≤ 6.0 V ≤ 6.0 V	≤ 6.0 V, w/3.9 kΩ, Load ≤ 6.0 V, w/3.9 kΩ, Load
V _{OD}	1.5 to 5.0 V, w/54 Ω load	\geq 2.0 V or \geq 0.5 V _{OCD} , w/100 Ω load	$\geq 2.0 \text{ V or } \geq 0.5 \text{ V}_{\text{OCD}},$ w/100 Ω load
ΔV_{OD}	< 200 mV	≤ 400 mV	< 400 mV
V _{CM}	-7.0 to +12 V	Not Specified	Not Specified
V _{OS}	$-1.0 < V_{OS} < 3.0 V$	≤ 3.0 V	≤ 3.0 V
ΔV_{OS}	< 200 mV	≤ 400 mV	< 400 mV
I _{OS}	\leqslant 250 mA for –7.0 to 12 V	≤ 150 mA to ground	≤ 150 mA to ground
I _{OLK}	Not Specified	≤ 100 μA to -0.25 V thru 6.0 V	\leqslant 100 μA to \pm 0.25 V
t _r , t _f	\leqslant 0.3 T _B , w/54 Ω /1150 pF load	$\leqslant 0.1~T_B~or \leqslant 20~ns,$ w/100 $\Omega~load$	\leqslant 0.1 T_B or \leqslant 20 ns, w/100 Ω load
	•		
V _{th}	± 200 mV	± 200 mV	± 300 mV
V _{bias}	≤ 3.0 V	≤ 3.0 V	≤ 3.0 V
	Z _{out} V _{OCD} V _{OD} ΔV _{OD} V _{CM} V _{OS} I _{OS} I _{OLK} t _r , t _f	$\begin{tabular}{ c c c c } \hline Z_{out} & Not Specified \\ \hline V_{OCD} & 1.5 to 6.0 V \\ < 6.0 V \\ \hline V_{OD} & 1.5 to 5.0 V, w/54 \Omega load \\ \hline \Delta V_{OD} & < 200 mV \\ \hline V_{CM} & -7.0 to +12 V \\ \hline V_{OS} & -1.0 < V_{OS} < 3.0 V \\ \hline \Delta V_{OS} & < 200 mV \\ \hline I_{OS} & \leq 250 mA \mbox{ for } -7.0 to 12 V \\ \hline I_{OLK} & Not Specified \\ \hline t_r, t_f & \leq 0.3 \mbox{ T}_B, w/54 \ \Omega/1150 \mbox{ pF} \\ \hline load \\ \hline V_{th} & \pm 200 \ mV \\ \hline \end{tabular}$	$ \begin{array}{ c c c c c } \hline Z_{out} & Not Specified & <100 \ \Omega \\ \hline V_{OCD} & 1.5 \ to \ 6.0 \ V & \leq 6.0 \ V \\ \hline V_{OCS} & <6.0 \ V & \leq 6.0 \ V \\ \hline V_{OD} & 1.5 \ to \ 5.0 \ V, \ w/54 \ \Omega \ load & \geqslant 2.0 \ V \ or \ \geqslant 0.5 \ V_{OCD}, \\ \hline w/100 \ \Omega \ load & \\ \hline \Delta V_{OD} & <200 \ mV & \leq 400 \ mV \\ \hline V_{CM} & -7.0 \ to \ +12 \ V & Not \ Specified \\ \hline V_{OS} & -1.0 \ $

NOTES: 1. Compliance with V.11 and X.27 (Blue book) output impedance requires external resistors in series with the outputs of the MC75172B and MC75174B.

-7.0 to 12 V

Spec number of U.L.

2. $T_B = Bit time.$

Input Common Mode Range

Dynamic Input Impedance

 V_{cm}

Rin

Additional Information

-7.0 to 7.0 V

≥4 kΩ

-7.0 to 7.0 V

≥4 kΩ

Copies of the EIA Recommendations (EIA–485 and EIA–422–A) can be obtained from the Electronics Industries Association, Washington, D.C. (202–457–4966). Copies of the CCITT Recommendations (V.11 and X.27) can be obtained from the United States Department of Commerce, Springfield, VA (703–487–4600).

ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
MC75172BDW		SOIC-20WB	
MC75172BDWG		SOIC-20WB (Pb-Free)	38 Units / Rail
MC75172BDWR2		SOIC-20WB	
MC75172BDWR2G	$T_{A} = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	SOIC-20WB (Pb-Free)	1000 / Tape & Reel
MC75174BDW		SOIC-20WB	
MC75174BDWG		SOIC-20WB (Pb-Free)	38 Units / Rail
MC75174BDWR2		SOIC-20WB	
MC75174BDWR2G	-	SOIC-20WB (Pb-Free)	1000 / Tape & Reel
MC75174BP		PDIP-16	
MC75174BPG		PDIP-16 (Pb-Free)	25 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PDIP-16 CASE 648-08 **ISSUE V**

NOTE 6

semi

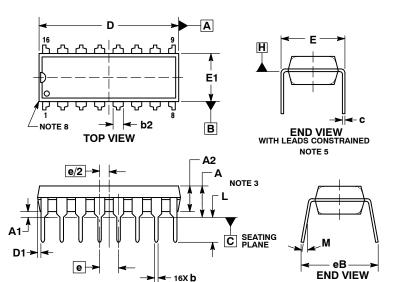
MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

DATE 22 APR 2015



SCALE 1:1



 \oplus 0.010 \otimes C A \otimes B \otimes

STYLE 1: STYLE 2: PIN 1. CATHODE CATHODE COMMON DRAIN COMMON DRAIN PIN 1. 2. 2. 3. CATHODE COMMON DRAIN З. COMMON DRAIN 4. 5. CATHODE 4. CATHODE 5. 6. CATHODE 6. COMMON DRAIN 7. CATHODE 7. COMMON DRAIN CATHODE COMMON DRAIN 8. 9. 8. ANODE 9. GATE 10. ANODE 10. SOURCE ANODE ANODE 11. 11. GATE SOURCE 12. 12. 13. ANODE 13. GATE 14. 15. ANODE ANODE 14. SOURCE GATE 15. 16 ANODE 16. SOURCE

SIDE VIEW

NOTES

- 1. 2
- З.
- VTES: DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: INCHES. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3. DIMENSIONS D, DI AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH. DIMENSION E IS MEASURED AT A POINT 0.016 RELOW DATUM 4
- DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR 5.
- TO DATUM C. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE 6.
- DIMENSION BY IS MEASURED AT THE LEAD THIS WITH THE LEADS UNCONSTRAINED. DATUM PLANE HIS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE 7.
- 8 CORNERS).

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP		1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005		0.13	
Е	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54 BSC	
eB		0.430		10.92
L	0.115	0.150	2.92	3.81
М		10°		10°

GENERIC **MARKING DIAGRAM***



XXXXX = Specific Device Code

- = Assembly Location
- WL = Wafer Lot
- YΥ = Year

Α

- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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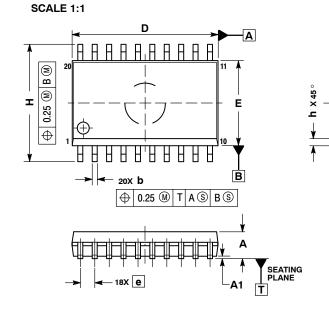
MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

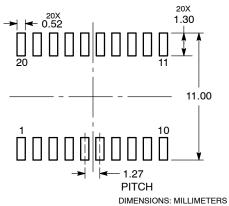


SOIC-20 WB CASE 751D-05 **ISSUE H**

DATE 22 APR 2015



RECOMMENDED SOLDERING FOOTPRINT*



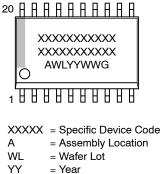
*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS. 2. INTERPRET DIMENSIONS AND TOLERANCES
- PER ASME Y14.5M, 1994. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- 4. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION 5. SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.35	2.65	
A1	0.10	0.25	
b	0.35	0.49	
C	0.23	0.32	
D	12.65	12.95	
E	7.40	7.60	
е	1.27 BSC		
н	10.05	10.55	
h	0.25	0.75	
L	0.50	0.90	
θ	0 °	7 °	

GENERIC **MARKING DIAGRAM***



ww = Work Week

G

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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